Ordering number : ENN8230



ON Semiconductor DATA SHEET

2SK3824— General-Purpose Switching Device Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 4V drive.
- · Motor drive, DC / DC converter.
- · Avalanche resistance guarantee.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		60	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		60	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	240	А
Allowable Power Dissipation	D-		1.75	W
	PD	Tc=25°C	60	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Energy (Single Pulse) *1	EAS		125	mJ
Avalanche Current *2	IAV		60	А

Note: *1 V_{DD}=20V, L=50μH, I_{AV}=60A

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0	60			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =60V, V _{GS} =0			1	μА
Gate-to-Source Leakage Current	IGSS	V _{GS} = ±16V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =30A	24	40		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =30A, V _{GS} =10V		11.5	15	mΩ
	R _{DS} (on)2	ID=30A, VGS=4V		16	22	mΩ

Marking: K3824 Continued on next page.

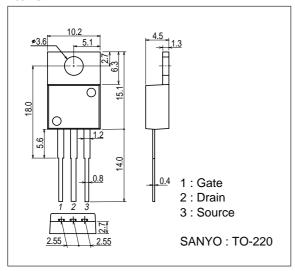
^{*2} L≤50μH, Single pulse

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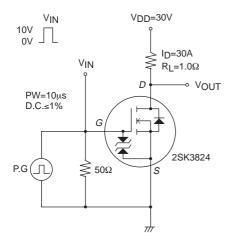
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		3500		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		500		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		350		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		26		ns
Rise Time	t _r	See specified Test Circuit.		230		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		255		ns
Fall Time	tf	See specified Test Circuit.		230		ns
Total Gate Charge	Qg	V _{DS} =30V, V _{GS} =10V, I _D =60A		67		nC
Gate-to-Source Charge	Qgs	V _{DS} =30V, V _{GS} =10V, I _D =60A		10.6		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =30V, V _{GS} =10V, I _D =60A		10		nC
Diode Forward Voltage	V _{SD}	I _S =60A, V _{GS} =0		1.07	1.5	V

Package Dimensions

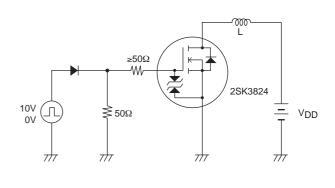
unit : mm 2052C

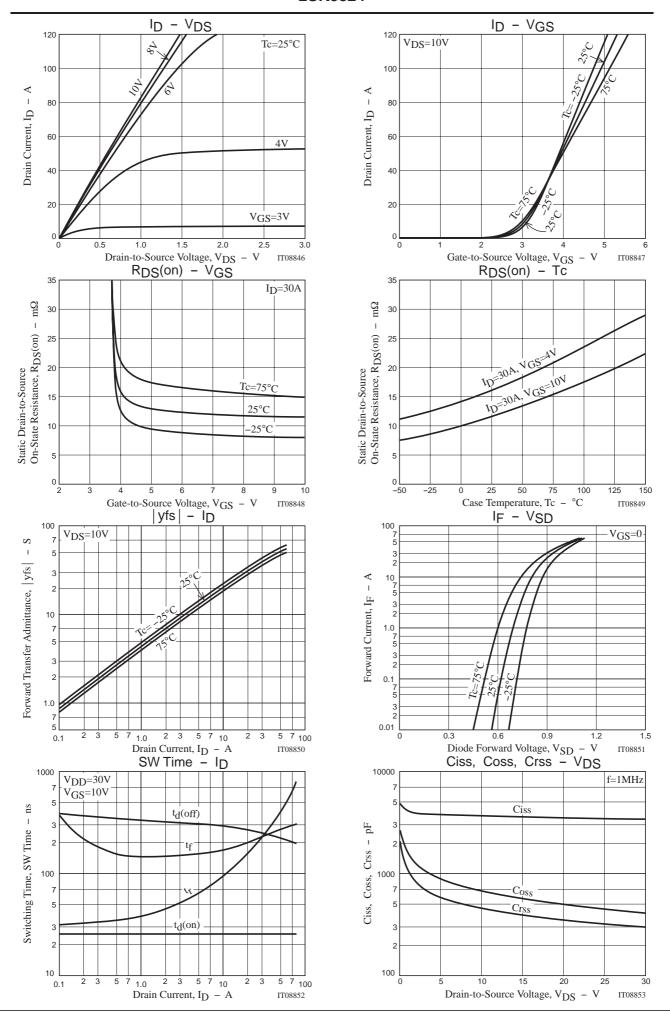


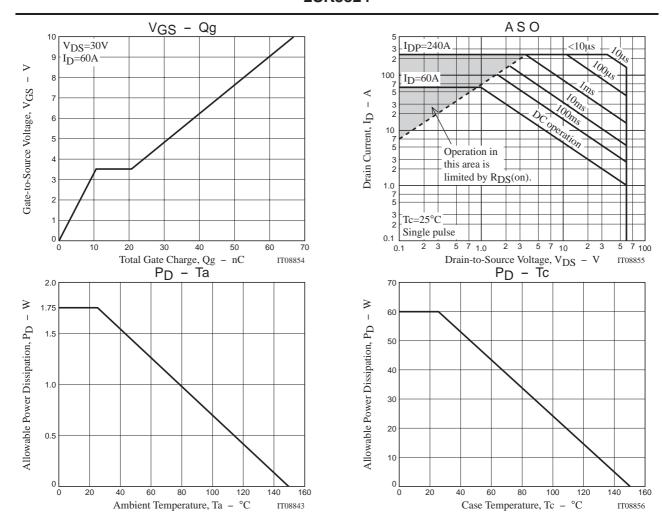
Switching Time Test Circuit



Avalanche Resistance Test Circuit







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